

BAP65-05W

Silicon PIN diode

Rev. 2 — 27 September 2010

Product data sheet

1. Product profile

1.1 General description

Two planar PIN diodes in a SOT323 small SMD plastic package.

1.2 Features and benefits

- Two elements in common cathode configuration
- High voltage, current controlled
- RF resistor for RF switches
- Low diode capacitance
- Low diode forward resistance (low loss)

1.3 Applications

- RF attenuators and switches
- Bandswitch for TV tuners
- Series diode for mobile communication transmit/receive switch

2. Pinning information

Table 1. Pinning

Pin	Description	Simplified outline	Graphic symbol	
1	anode (a ₁)			
2	anode (a ₂)	1 2	3	
3	common cathode		1 2 sym136	

3. Ordering information

Table 2. Ordering information

Type number	Package				
	Name	Description	Version		
BAP65-05W	-	plastic surface-mounted package; 3 leads	SOT323		



4. Marking

Table 3. Marking codes

Type number	Marking code
BAP65-05W	V6-

5. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_R	continuous reverse voltage		-	30	V
I _F	continuous forward current		-	100	mA
P _{tot}	total power dissipation	T _s ≤ 90 °C	-	240	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-65	+150	°C
T _{amb}	ambient temperature		-40	+85	°C

6. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
R _{th j-s}	thermal resistance from junction to soldering point		250	K/W

7. Characteristics

Table 6. Characteristics

 $T_j = 25$ °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{F}	forward voltage	$I_F = 50 \text{ mA}$	-	0.9	1.1	V
I _R	reverse leakage current	V _R = 20 V	-	-	20	nA
C _d	diode capacitance	$V_R = 0 V; f = 1 MHz$	-	0.7	-	pF
		$V_R = 1 V$; $f = 1 MHz$	-	0.575	0.9	pF
		$V_R = 3 V; f = 1 MHz$	-	0.525	8.0	pF
		V _R = 20 V; f = 1 MHz	-	0.425	-	pF
r _D	diode forward resistance	$I_F = 1 \text{ mA}; f = 100 \text{ MHz}$	-	1	-	Ω
		$I_F = 5 \text{ mA}$; $f = 100 \text{ MHz}$	<u>[1]</u> _	0.65	0.95	Ω
		$I_F = 10 \text{ mA}; f = 100 \text{ MHz}$	<u>[1]</u> _	0.56	0.9	Ω
		$I_F = 100 \text{ mA}$; $f = 100 \text{ MHz}$	-	0.35	-	Ω
$ s_{21} ^2$	isolation	$V_R = 0$; $f = 900 \text{ MHz}$	-	9.3	-	dB
		$V_R = 0$; $f = 1800 \text{ MHz}$	-	5.3	-	dB
		V _R = 0; f = 2450 MHz	-	3.5	-	dB

BAP65-05W

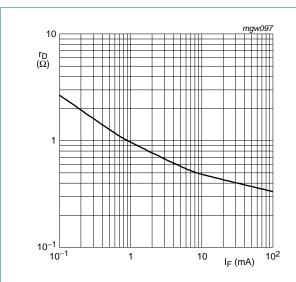
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Table 6. Characteristics ...continued $T_i = 25$ °C unless otherwise specified.

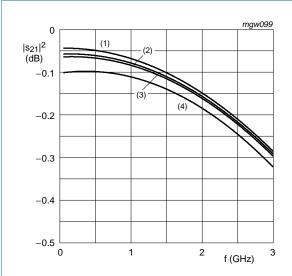
,						
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$ s_{21} ^2$	insertion loss	$I_F = 1 \text{ mA}; f = 900 \text{ MHz}$	-	0.11	-	dB
		I _F = 1 mA; f = 1800 MHz	-	0.17	-	dB
		I _F = 1 mA; f = 2450 MHz	-	0.24	-	dB
$ s_{21} ^2$	insertion loss	$I_F = 5 \text{ mA}; f = 900 \text{ MHz}$	-	0.08	-	dB
		$I_F = 5 \text{ mA}$; $f = 1800 \text{ MHz}$	-	0.14	-	dB
		$I_F = 5 \text{ mA}$; $f = 2450 \text{ MHz}$	-	0.21	-	dB
$ s_{21} ^2$	insertion loss	$I_F = 10 \text{ mA}; f = 900 \text{ MHz}$	-	0.08	-	dB
		$I_F = 10 \text{ mA}; f = 1800 \text{ MHz}$	-	0.14	-	dB
		$I_F = 10 \text{ mA}; f = 2450 \text{ MHz}$	-	0.21	-	dB
$ s_{21} ^2$ in	insertion loss	$I_F = 100 \text{ mA}; f = 900 \text{ MHz}$	-	0.06	-	dB
		$I_F = 100 \text{ mA}; f = 1800 \text{ MHz}$	-	0.13	-	dB
		I _F = 100 mA; f = 2450 MHz	-	0.2	-	dB
τ լ	charge carrier life time	when switched from I_F = 10 mA to I_R = 6 mA; R_L = 100 Ω ; measured at I_R = 3 mA	-	0.17	-	μS
L _S	series inductance	$I_F = 100 \text{ mA}; f = 100 \text{ MHz}$	-	1.4	-	nΗ

^[1] Guaranteed on AQL basis: inspection level S4, AQL 1.0.



 $f = 100 \text{ MHz}; T_j = 25 \text{ }^{\circ}\text{C}$

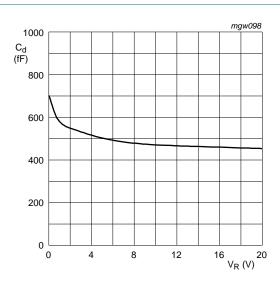
Fig 1. Forward resistance as a function of forward current; typical values



- (1) $I_F = 100 \text{ mA}$
- (2) $I_F = 10 \text{ mA}$
- (3) $I_F = 5 \text{ mA}$
- (4) $I_F = 1 \text{ mA}$

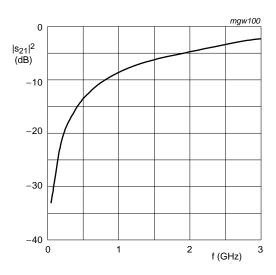
Diode inserted in series with a 50 Ω stripline circuit and biased via the analyzer Tee network. T $_{\rm amb}$ = 25 $^{\circ} C$.

Fig 3. Insertion loss ($|s_{21}|^2$) of the diode in on-state as a function of frequency; typical values



 $f = 1 \text{ MHz}; T_j = 25 \text{ }^{\circ}\text{C}$

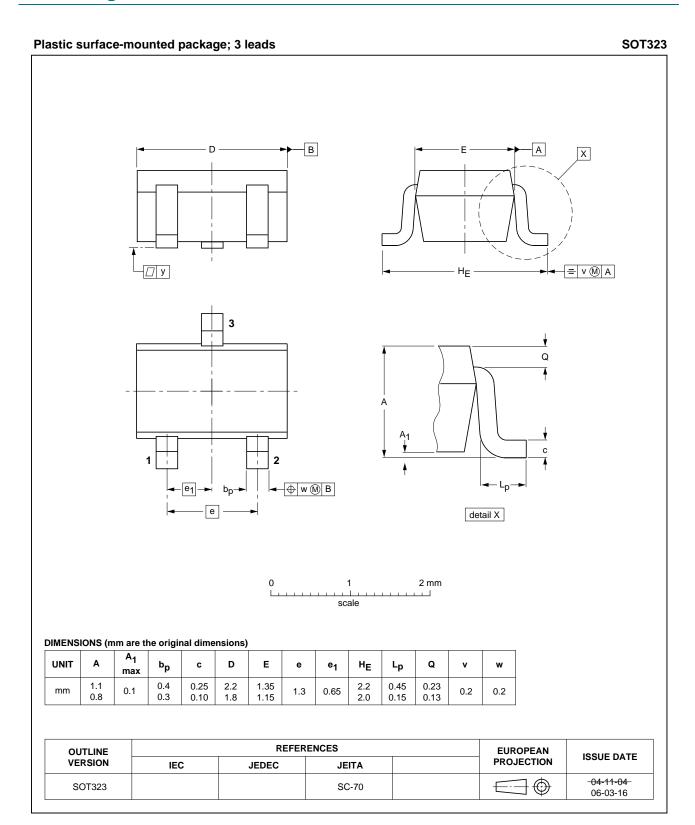
Fig 2. Diode capacitance as a function of reverse voltage; typical values



Diode zero biased and inserted in series with a 50 Ω stripline circuit. $\rm T_{amb}$ = 25 $^{\circ}\rm C.$

Fig 4. Isolation ($|s_{21}|^2$) of the diode in off-state as a function of frequency; typical values

Package outline



Package outline SOT323 Fig 5.

9. Revision history

Table 7. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BAP65-05W v.2	20100927	Product data sheet	-	BAP65-05W v.1
Modifications:		of this data sheet has been of NXP Semiconductors.	redesigned to comply v	vith the new identity
	 Legal texts 	have been updated.		
	• <u>Figure 5</u> : p	ackage outline drawing has	been updated to the late	est version.
	• Table 4 "Li	miting values": added T _{amb} (ambient temperature).	
BAP65-05W v.1 (9397 750 08115)	20010507	Product specification	-	-

10. Legal information

10.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions"
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